## NSN 5961-01-080-1463



Transistor - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-080-1463 **Inclosure Material:** Metal **Overall Length:** Between 0.250 inches and 0.450 inches Overall Diameter: 0.875 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 collector to base voltage, dc and 300.0 collector to emitter voltage, dc and 5.0 emitter to base voltage, dc **Current Rating Per Characteristic:** Between 10.00 amperes source cutoff current and 30.00 amperes source cutoff current **Power Rating Per Characteristic:** 200.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 94117-1071803 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 1 case and 2 pin Shelf Life: N/a

**Unit Of Measure:** 

**Demilitarization:** 

No

Fiig:

A110a0